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Synthesis, Structure, and Fluxional Behavior of **Base-Stabilized Silyl(silylene)tungsten Complexes**

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Received February 20, 1998

Summary: Donor-stabilized silyl(silylene)tungsten complexes $Cp(OC)_2W(SiMe_3)$ (=SiMe₂·Base) ($Cp = \eta - C_5H_5$, Base = HMPA (1a) and THF (1b)) have been synthesized by photolysis of C_6D_6 solutions containing $CpW(CO)_3$ -SiMe₂SiMe₃ and bases. The double-bond character of the tungsten-silylene bonding was revealed by the significant downfield shift of the ²⁹Si NMR signal as well as the large ${}^{1}J_{WSi}$ value for the silvlene ligand ($\delta = 92.5$ ppm (${}^{I}J_{WSi} = 121 \text{ Hz}$) for **1a** and $\delta = 144.7 \text{ ppm}$ (${}^{I}J_{WSi} = 132 \text{ Hz}$) for **1b**) and also the short W–Si distance between tungsten and the silylene ligand (2.481(3) Å) of 1a. Complex 1b shows fluxional behavior due to intramolecular 1,3-methyl migration from the silyl ligand to the silylene ligand.

It has been known for many years that transitionmetal complexes catalyze the redistribution of substituents on silicon atoms in organosilicon compounds.^{1,2} Silylene complexes have often been postulated to account for the transition-metal-catalyzed redistribution.^{1,3} A possible mechanism for the redistribution involves the formation of an intermediate silyl(silylene)metal complex of the type $L_n M(=SiR_2)SiR_3$ followed by the intramolecular 1,3-substituent migration from the silyl group to the silylene ligand in the silyl(silylene) complex. Pannell,⁴ the present authors,⁵ Turner,⁶ and others⁷ have reported convincing evidence for the formation of silyl(silylene) intermediates and the 1,3migration process in the silvl(silvlene) complexes. However, attempts to isolate the silvl(silvlene) intermediate have not been successful due to its thermal instability, although intramolecularly base-stabilized silyl(silylene)metal complexes^{8,9} and photolabile silyl(silylene)iron complexes stabilized by complexation to chromium carbonyl¹⁰ have been reported.

Very recently, we have isolated an external basestabilized silyl(silylene)iron complex and directly observed 1,3-methyl migration from the silyl group to the silylene ligand using a VT NMR technique.¹¹ However, the extreme sensitivity of the complex toward air and moisture prevented further investigation, such as crystal structure determination and reactivity studies. Thus, we have sought a stable silyl(silylene)metal system. Here, we report the synthesis of the first external base-stabilized silyl(silylene)tungsten complexes Cp- $(OC)_2W(SiMe_3)$ (=SiMe₂·Base) (Cp = η -C₅H₅, Base = HMPA (hexamethylphosphoric triamide, 1a) and THF (**1b**)). The tungsten complexes are relatively stable compared to the iron complex. The crystal structure of 1a and the fluxional behavior of complex 1b are also reported.

Irradiation of a C₆D₆ solution containing CpW(CO)₃-SiMe₂SiMe₃ (2)¹² and 3 equiv of THF in a Pyrex NMR sample tube with a 450 W medium-pressure mercury arc lamp afforded a THF-coordinated silyl(silylene)tungsten complex 1b almost quantitatively (eq 1).¹³ The



HMPA-coordinated silyl(silylene)tungsten complex 1a was synthesized by a similar procedure.¹⁴ However, in this case, a small amount of unidentified byproduct was

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⁽¹³⁾ **1b**: A toluene solution (ca. 3 mL) of **2** (0.10 g, 0.22 mmol) and

THF (0.5 mL) placed in the Pyrex sample tube described above was irradiated for 1 h. After irradiation, volatiles were removed from the reaction mixture under reduced pressure. The residue was recrystal-lized from toluene/hexane to afford pale yellow crystals of **1b** (0.022 g 12cd from totaler be and a part yend with scalars of years of years of (3.5 groups), 0.043 mmol, 20%): ¹H NMR (300 MHz, THF- d_8 , room temperature) δ 5.03 (s, 5H, Cp), 0.73 (s, 6H, SiMe₂), 0.36 (s, 9H, SiMe₃); ¹³C NMR (75.5 MHz, THF- d_8 , room temperature) δ 226.5 (CO), 87.7 (Cp), 9.8 (SiMe₂), 6.7 (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₂), 6.7 (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₂), 6.7 (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₂), 6.7 (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₂), 6.7 (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₂), 6.7 (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₂), 6.7 (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₂), 6.7 (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8 , room temperature) (SiMe₃); ²³Si NMR (59.6 MHz, THF- d_8); ²³Si NMR (59.6 MHz, THF- d_8); ²³Si NMR (59.6 MHz); ²³Si NMR (59.6 MLZ); ²³Si NMR (59.6 MLZ); ²³Si NMR (59.6 MLZ δ 144.7 ($I_{WSI} = 132$ Hz, SiMe₂), 18.2 ($I_{WSI} = 54$ Hz, SiMe₃); IR (THF- d_8) v_{C0} 1868, 1792 cm⁻¹. Satisfactory results of elemental analysis for complex 1b could not be obtained due to its extreme sensitivity toward air and moisture.



Figure 1. ORTEP drawing of 1a with thermal ellipsoids shown at the 50% probability level. Selected bond distances (Å) and angles (deg): W-Si(1) 2.481(3), W-Si(2) 2.553(3), W-C(1) 1.927(10), W-C(2) 1.924(9), Si(1)-C(6) 1.876(10), Si(1)-C(7) 1.879(10), Si(1)-O(3) 1.774(6), Si(2)-C(3) 1.881-(10), Si(2)-C(4) 1.890(11), Si(2)-C(5) 1.892(10), O(1)-C(1)1.167(11), O(2)-C(2) 1.181(10), P-O(3) 1.515(6), Si(1)-W-Si(2) 128.76(8), C(2)-W-C(1) 99.7(4), C(6)-Si(1)-C(7) 105.1(5), C(6)-Si(1)-W 115.9(4), C(7)-Si(1)-W 118.4(3), O(3)-Si(1)-W 111.6(2), P-O(3)-Si(1) 147.2(4).

also formed. Complexes 1a and 1b were isolated as airsensitive, pale yellow crystals in 20% yield. Complex 1a was fully characterized by NMR, IR, and mass spectroscopy, elemental analysis, and X-ray crystal structure analysis.

The X-ray crystal structure of **1a** (Figure 1)¹⁵ revealed that the silvlene ligand is trans to the silvl group (Si-(1)-W-Si(2) 128.76(8)°), which contrasts with the cis geometry of the base-bridged bis(silylene)tungsten complexes Cp(OC)₂W{SiMe₂···Base···SiMe₂} (3; Si-W-Si 62–64°).⁸ The *trans* geometry of **1a** is attributable to the steric repulsion between the silvl group and the HMPA-coordinated silvlene ligand. A similar trans configuration was commonly observed in phosphinesubstituted silvltungsten complexes of the type CpW-(CO)₂(PR₃)SiR'₃.¹⁷ The tungsten-silylene bond (W-Si(1) 2.481(3) Å) in 1a is significantly shorter than that

 P_2_1/n , a = 9.236(4) Å, b = 18.837(5) Å, c = 15.007(2) Å, $\beta = 98.921-(18)^\circ$, V = 2579.3(13) Å³, Z = 4, $D_c = 1.585$ g/cm³. The structure was solved by Patterson and Fourier transform methods and refined by full-matrix least-squares techniques on all F^2 data (5923 unique reflections) using SHELX-97.¹⁶ R1 = 0.049 and wR2 = 0.105 for 3631 reflections with $I > 2.0\sigma(I)$.

(16) Sheldrick, G. M. SHELX-97, Program for Crystal Structure



of the tungsten-silvl bond (W-Si(2) 2.553(3) Å) in the same complex and those of structurally similar alkylsilyltungsten complexes (2.53–2.63 Å).¹⁷ The W–Si(1) bond distance is slightly shorter than those of the donorbridged bis(silylene)tungsten complexes 3 (2.49-2.51 Å),^{8g} however, slightly longer than that in a (perchlorodisilanyl)tungsten complex (η-C₅Me₅)W(CO)₂(PMe₃)-SiCl₂SiCl₃ (2.469(2) Å).^{17b} The Si(1)–O(3) distance



3: Base = NEt₂, OMe

(1.774(6) Å) is much longer than the usual Si–O single bonds (1.58–1.70 Å)¹⁸ and in the range of the reported Si-O(HMPA) distance of the HMPA-coordinated silyleneiron and -chromium complexes (1.67-1.78 Å).¹⁹ These structural data clearly demonstrate that the W-Si(1) and W-Si(2) bonds take on a double-bond character and a single-bond character, respectively, and the Si(1)-O(3) bond is regarded as a dative bond.

The double-bond character of the tungsten-silylene bonding in **1** is also supported by the significant downfield shift of the ²⁹Si NMR signals as well as the large coupling constants between 29 Si and 183 W ($\delta = 92.5$ ppm $({}^{1}J_{WSi} = 121 \text{ Hz})$ for **1a** and $\delta = 144.7 \text{ ppm} ({}^{1}J_{WSi} = 132 \text{ Hz})$ Hz) for **1b**) compared to those of the silvl groups in **1** (δ = 18–19 ppm, ${}^{1}J_{WSi}$ = 50–58 Hz) and the structurally similar silvltungsten complexes ($\delta = -44-59$ ppm, ¹ J_{WSi} = 41–65 Hz).¹⁷ Interestingly, the ${}^{1}J_{WSi}$ values for the silvlene ligands in 1 are apparently larger than those of the donor-bridged bis(silylene)tungsten complexes 3 $({}^{1}J_{WSi} = 91-100 \text{ Hz}).{}^{8g}$ This indicates a higher bond order of the tungsten-silylene bonding in **1** than in **3**. In the latter complex, the formal bond order is expected to be 1.5.

The formation of **1** can be explained by a mechanism shown in Scheme 1: (i) Photochemical dissociation of a carbonyl ligand from 2 to give a 16-electron intermediate **A**, (ii) 1,2-shift of the silvl group to the coordinatively unsaturated tungsten to form base-free silvl(silvlene)tungsten complex **B**, and (iii) coordination of a base to the electron-deficient silvlene ligand to form 1.

^{(14) 1}a: A Pyrex sample tube (10 mm o.d., 8 mm i.d.) with a Teflon vacuum valve and a ground-glass joint was charged with a toluene solution (ca. 4 mL) of 2 (0.084 g, 0.18 mmol) and HMPA (0.033 mL, 0.18 mmol). The solution was subjected to three freeze-pump-thaw cycles and irradiated for 10 h. Volatiles were evaporated under high vacuum. The residue was extracted with hexane to remove insoluble black solids. The extract was concentrated until a small amount of crystals appeared in solution. Cooling the mixture at -30 °C afforded pale yellow crystals of **1a** (0.022 g, 0.036 mmol, 20%): ¹H NMR (300 MHz, C₆D₆, room temperature) δ 5.00 (s, 5H, Cp), 2.15 (d, 18H, ³J_{PH} = 10.2 Hz, HMPA), 1.04 (s, 9H, SiMe₃), 0.90 (s, 6H, SiMe₂); ¹³C NMR (75.5 MHz, C₆D₆, room temperature) & 228.3 (CO), 86.6 (Cp), 36.6 (d, $^{2}J_{PC} = 5.0$ Hz, HMPA), 12.4 (SiMe₂), 7.6 (SiMe₃); ²⁹Si NMR (59.6 MHz, C₆D₆, room temperature) δ 92.5 (d, ²J_{PSi} = 28.8 Hz, ¹J_{WSi} = 121 Hz, $C_{6}D_{6}$, 160 in temperature) of 32.5 (d, 5_{12}) = 23.5 Hz, 5_{12} Hz, 121 Hz, SiMe₂), 18.6 (s, ${}^{1}J_{WSi} = 59$ Hz, SiMe₃); IR ($C_{6}D_{6}$) v_{C0} 1857, 1778 cm⁻¹; MS (EI, 70 eV) m/z 436 (M⁺ – HMPA, 5.49). Anal. Calcd for $C_{18}H_{38}O_{3}N_{3}PSi_{2}W$: C, 35.12; H, 6.22. Found: C, 35.19; H, 6.03. (15) Crystal data for **1a**: $C_{18}H_{38}O_{3}N_{3}PSi_{2}W$, monoclinic, space group

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Figure 2. Variable-temperature ¹H NMR spectra (300 MHz) of **1b** measured in toluene- d_8 . Asterisk (*) denotes $C_6D_5CD_2H$.

The THF-coordinated silyl(silylene)tungsten complex **1b** exhibits a dynamic process in solution. The ¹H NMR spectrum of the complex **1b** in toluene- d_8 at 230 K shows two singlet signals in the SiMe region at 0.71 and 1.04 ppm, which are assignable to the SiMe₂ and SiMe₃ ligands, respectively (Figure 2). As the temperature is raised from 230 K, the SiMe signals broaden, coalesce, and become a singlet peak at 320 K. The signals for the coordinated THF that appear at 0.95 and 3.15 ppm at 230 K also broaden at 260 K and become sharp signals at 280 K. These spectral changes clearly show that the intramolecular 1,3-methyl migration from the SiMe₃ group to the SiMe₂ ligand and exchange between the coordinated THF and a trace amount of free THF take place in the NMR time scale.

A proposed mechanism for the 1,3-methyl migration is given in Scheme 2: (i) Dissociation of the coordinated THF molecule from **1b** to give a base-free silyl(silylene)tungsten intermediate **B**, (ii) 1,3-methyl migration from the SiMe₃ group to the electron-deficient silylene ligand to afford intermediate **B**', which proceeds most likely via a symmetric transition state (or intermediate) **C**, and (iii) recombination of a THF molecule with the silylene ligand in **B**' to reproduce **1b**. This mechanism



is essentially the same as that proposed previously for the 1,3-methyl migration in the base-stabilized silyl-(silylene)iron complex.¹¹

Interestingly, the HMPA-coordinated complex **1a**, in contrast to the THF-coordinated complex **1b**, does not show the dynamic behavior due to the 1,3-methyl migration under similar experimental conditions. This can be explained by the fact that the coordination of the HMPA molecule to the electron-deficient silylene ligand is much stronger than that of the THF molecule, which prevents the generation of the base-free silyl(silylene)tungsten intermediate **B**. Indeed, addition of HMPA to a solution of the THF-coordinated complex **1b** caused base substitution to produce the HMPA-coordinated complex **1a** almost quantitatively. The reactivity of the silyl(silylene)tungsten complexes can be controlled by the nature of the donor coordinated to the silylene ligand.

Acknowledgment. This work was supported by Grants-in-Aid for Scientific Research (Grant No. 09440223) from the Ministry of Education, Science, Sports, and Culture of Japan.

Supporting Information Available: Text giving crystal structure determination details and tables giving crystal data, atomic coordinates and equivalent isotropic displacement parameters of non-hydrogen atoms, bond lengths and angles, anisotropic displacement parameters, and hydrogen coordinates and isotropic displacement parameters for **1a** (7 pages). Ordering information is given on any current masthead page.

OM980121W